OMRON

MOS FET Relay

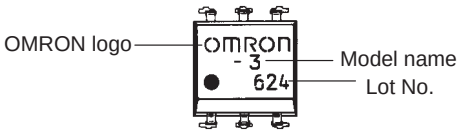
G3VM-W

G3VM Low-cost Series (Two-output Models)

- New G3VM Series with 350-V-output dielectric strength.
- Two-output models now available.
- Approved Standards: UL1577

Ordering Information

■ Appearance



Note: "G3VM" is not printed on the actual product

■ Model Number Legend

G3VM-□□

1 2

1. Load Voltage

W: Load voltage, 350 VDC or 350 VAC min.

2. Terminal

F: Surface-mounting terminals

None: PCB terminals

Contact form	Terminals	Load voltage (peak value)	Model	Number per stick
DPST-NO	PCB terminals	350 VAC	G3VM-W–S	50
	Surface-mounting terminals		G3VM-WF–S	50

Specifications

■ Absolute Maximum Ratings (Ta = 25°C)

Item			Symbol	Rating	Unit
Input	LED forward current		I_F	50	mA
	LED forward current reduction rate (Ta≧25°C)		ΔI_F/°C	–0.5	mA/°C
	Repetitive peak LED forward current (100 μs pulse)		I_{FP}	1	A
	LED reverse voltage		V_R	5	V
	Connection temperature		T_j	125	°C
Output	Output dielectric strength		V_{OFF}	350	V
	Continuous load current	Current per channel	I_O	120	mA
	ON current reduction rate (Ta≧25°C)	Current per channel	ΔI_{ON}/°C	–1.2	mA/°C
	Connection temperature		T_j	125	°C
Storage temperature			T_{stg}	–55 to 100	°C
Operating temperature			T_a	–20 to 85	°C
Soldering temperature (10 s)			T_{sol}	260	°C
Dielectric strength (AC for 1 min with ambient humidity of 60% or less) (see note)			V_{I-O}	2,500	V_{rms}

Note: Apply voltage between a group of pins 1, 2, and 3, 4 and that of pins 8, 7 and 6, 5.

■ Recommended Operating Conditions

Item	Symbol	Minimum	Typical	Maximum	Unit
Operating voltage	V_{DD}	---	---	280	V
Forward current	I_F	5.0	7.5	25	mA
Continuous load current	I_O	---	---	100	mA
Operating temperature	Ta	–20	---	65	°C

■ Electrical Characteristics (Ta = 25°C)

Item		Symbol	Measurement conditions	Minimum	Typical	Maximum	Unit
Input	LED forward current	V_F	I_F=10 mA	1.0	1.15	1.3	V
	Reverse current	I_R	V_R=5 V	---	---	10	μA
	Capacity between terminals	C_T	V=0, , f=1MHZ	---	30	---	pF
Output	Current leakage when the relay is open	I_{LEAK}	V_{OFF}=350 V	---	---	1	μA

■ Connection Characteristics (Ta = 25°C)

Item	Symbol	Measurement conditions	Minimum	Typical	Maximum	Unit
Maximum resistance with output ON	R_{ON}	I_{ON}=100 mA, I_F=10 mA	---	22	35	Ω
		I_{ON}=20 to 100 mA, I_F=10 mA	---	26	40	

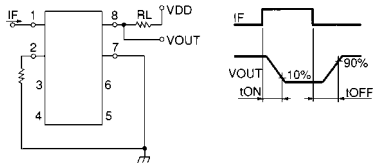
■ Insulation Characteristics (Ta = 25°C)

Item	Symbol	Measurement conditions	Minimum	Typical	Maximum	Unit
Floating capacity between I/O terminals	C_{I-O}	V_S=0, f=1MH$_Z$	---	0.8	---	pF
Insulation resistance	R_{I-O}	V_S=0, operating ambient humidity: ≦60%	5 x 10^{10}	10^{14}	---	Ω
Dielectric strength	V_{I-O}	AC for 1 min	2,500	---	---	V_{rms}
		AC for 1 s in oil	---	5,000	---	
		DC for 1 min in oil	---	5,000	---	V_{dc}

■ Switching Characteristics (Ta = 25°C)

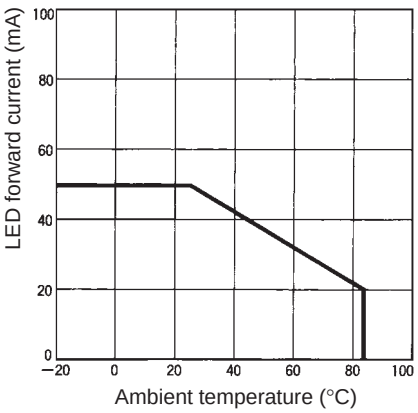
Item	Symbol	Measurement conditions	Minimum	Typical	Maximum	Unit
Turn-on time	t_{ON}	R_L=200 Ω V_{DD}=20 V, I_F=10 mA (see note)	---	---	1	ms
Turn-off time	t_{OFF}		---	---	1	

Note: Switching Time Measuring Circuit

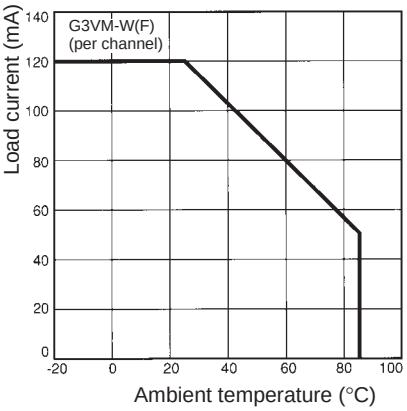


Engineering Data

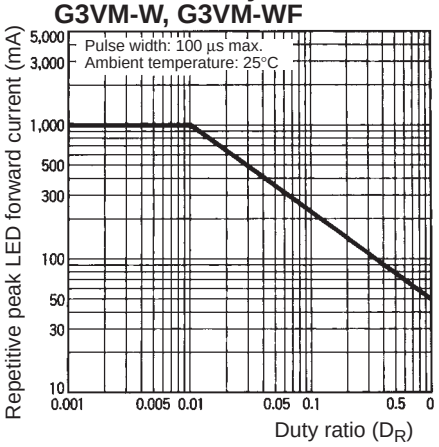
LED Forward Current vs. Ambient Temperature G3VM-W, G3VM-WF



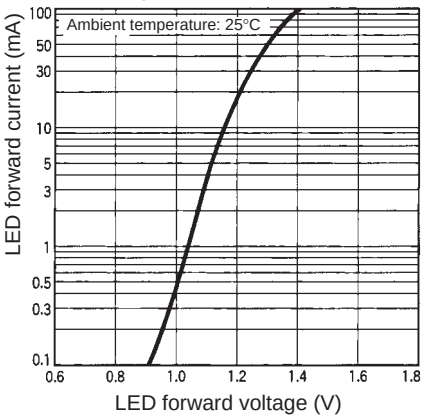
Load Current vs. Ambient Temperature Characteristics G3VM-W, G3VM-WF



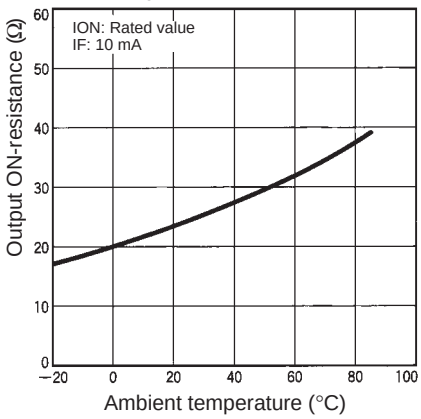
Repetitive Peak LED Forward Current vs. Duty Ratio G3VM-W, G3VM-WF



LED Forward Current vs. LED Forward Voltage G3VM-W, G3VM-WF



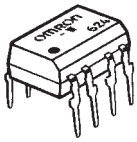
Output ON-resistance vs. Ambient Temperature G3VM-W, G3VM-WF



Dimensions

Note: All units are in millimeters unless otherwise indicated.

G3VM-W



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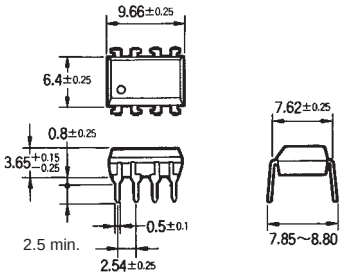
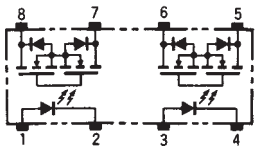
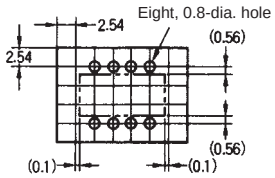


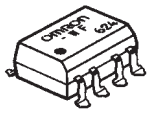
Terminal Arrangement/ Internal Connections (Top View)



PCB Dimensions (Bottom View)



G3VM-WF



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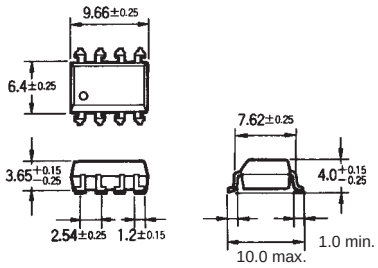

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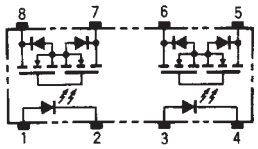

Actual Mounting Pad Dimensions (Recommended Value, Bottom View)